RICOH

R3132x/R3133x SERIES

LOW VOLTAGE DETECTOR WITH BUILT-IN DELAY CIRCUIT

NO.EA-093-160314

OUTLINE

R3132x/R3133x Series are CMOS-based low voltage detector ICs with built-in delay circuit, high detector threshold accuracy, and ultra low supply current, which can operate at low voltage.

These ICs can be used as system reset generators, and each of these ICs consists of a voltage reference, a comparator, resistors for setting voltage detector threshold, an output driver transistor, manual reset circuit, and an output delay generator.

Detector threshold is fixed internally with high accuracy and requires no adjustment. When a supply voltage crosses a setting detector threshold voltage from a high value to a lower value, this IC generates reset signal.

R3132x Series output "L" at its detect, while R3133x Series output "H".

Since each of R3132x/R3133x Series embeds an output delay generator, during a setting 240ms delay time, which is fixed in the IC, this IC keeps the reset condition after they are released. Released conditions are the case when a supply voltage crosses a setting detector threshold voltage from a low value to a higher value, or when this IC is released from manual reset.

Two output types, Nch open drain type and CMOS type, are available.

Since the package for these ICs are ultra small SC-82AB package and SON1612-6, high density mounting of the ICs on board is possible.

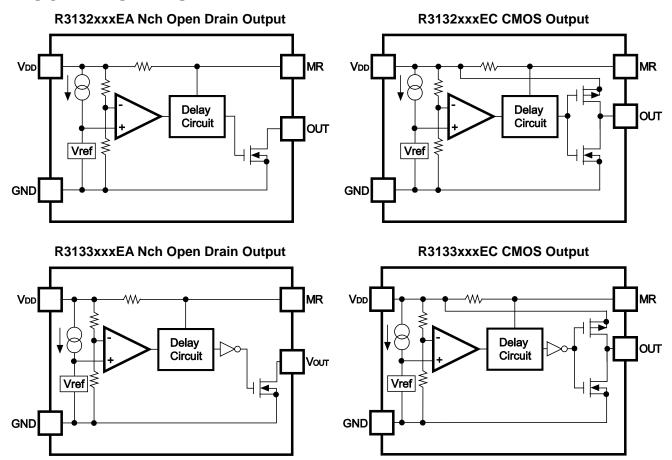
FEATURES

| Supply current | Τyp. 0.8μA (R313xx27x: V _{DD} =3.0V) |
|---|--|
| Operating Voltage Range | 0.8V to 6.0V (Topt=25°C) |
| Detector Threshold | Setting with a step of 0.1V in the range of 1.0V |
| | to 5.0V is possible. Further, 2.32V, 2.63V, 2.93V, |
| | 3.08V, 4.38V, and 4.63V can be provided as |
| | standard. |
| Embedded Power on Reset Delay Time Circuit | Typ. 240ms |
| Detector Threshold Accuracy | ±2.0% |
| Released Delay Time Accuracy | ±15.0% |
| Temperature-Drift Coefficient of Detector Threshold | Typ. ±100ppm/°C |
| Output Types | Nch Open Drain and CMOS |
| Packages | SC-82AB, SON1612-6 |

APPLICATIONS

- · CPU and Logic Circuit Reset
- · Battery Checker
- Window Comparator
- · Wave Shaping Circuit
- · Battery Back-up Circuit
- · Power Failure Detector

BLOCK DIAGRAMS



SELECTION GUIDE

The package type, the detector threshold, the output type and the taping type for the ICs can be selected at the users' request.

| Product Name | Package | Quantity per Reel | Pb Free | Halogen Free |
|--|-----------|----------------------|---------|--------------|
| R3132DxxE*(y)-TR-FE R3133DxxE*(y)-TR-FE | SON1612-6 | 4,000 pcs | Yes | Yes |
| R3132QxxE*(y)-TR-FE R3133QxxE*(y)-TR-FE | SC-82AB | 3,000 pcs | Yes | Yes |

xx: The detector threshold can be designated in the range from 1.0V(10) to 5.0V(50) in 0.1V steps.

(2.32V, 2.63V, 2.93V, 3.08V, 4.38V, 4.63V)

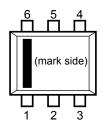
Ex. If the detector threshold is 2.63V, R3132x26E*3-TR-FE.

- * : Designation of Output Type
 - (A) Nch Open Drain
 - (C) CMOS

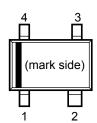
y: If the detector threshold includes the 3rd digit, indicate the digit of 0.01V.

PIN CONFIGURATIONS

• SON1612-6



• SC-82AB



PIN DESCRIPTIONS

• SON1612-6

| Pin No | Symbol | Pin Description |
|--------|-----------------|---|
| 1 | V _{DD} | Input Pin |
| 2 | GND | Ground Pin |
| 3 | MR | Manual Reset Input Pin Active at "L" input. Pulled up via $1M\Omega$. If MR pin is not necessary, open this node, or connect to V_{DD} . |
| 4 | OUT | Output Pin R3132D Series:"L" at detection R3133D Series:"H" at detection |
| 5 | GND | Ground Pin |
| 6 | NC | No Connection |

• SC-82AB

| Pin No | Symbol | Pin Description |
|--------|-----------------|---|
| 1 | GND | Ground Pin |
| 2 | OUT | Output Pin R3132Q Series :"L" at detection R3133Q Series :"H" at detection |
| 3 | MR | Manual Reset Input Pin Active at "L" input. Pulled up via $1M\Omega$. If MR pin is not necessary, open this node, or connect to V_{DD} . |
| 4 | V _{DD} | Input Pin |

ABSOLUTE MAXIMUM RATINGS

| Symbol | Item | Rating | Unit |
|-----------------|--|---------------------------------|-------|
| V _{DD} | Supply Voltage | 6.5 | V |
| Vout | Output Voltage (Nch Open Drain Output) | Vss-0.3 to 6.5 | V |
| VOUT | Output Voltage (CMOS Output) | Vss-0.3 to V _{DD} +0.3 | V |
| Vmr | Input Voltage | Vss-0.3 to V _{DD} +0.3 | V |
| louт | Output Current | 20 | mA |
| Pp | Power Dissipation (SON1612-6)*1, *2 | 500 | mW |
| PD | Power Dissipation (SC-82AB)*2 | 380 | IIIVV |
| Topt | Operating Temperature Range | -40 to 85 | °C |
| Tstg | Storage Temperature Range | -55 to 125 | °C |
| Tsolder | Soldering Temperature | 260°C, 10s | |

^{*1)} This specification is at mounted on board.

 P_D depends on conditions of mounting on board. This specification is based on the measurement at the condition below:

*Measurement Conditions

Environment: Mounted on board (Wind velocity 0m/s)

Board Material: FR-4 (2-layer)

Board dimensions: 40mm x 40mm x t1.6mm

Copper Area: 50%

*2) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

ELECTRICAL CHARACTERISTICS

Topt=25°C

| Symbol | Item | Те | st Conditions | Min. | Тур. | Max. | Unit |
|---------------------------------|---|---|---|-------------------------|------|-------------------------|------------|
| | | R3132 | Topt=25°C | 0.75 | | 6.0 | |
| V _{DD} | Operating Voltage | K3132 | –40°C≤Topt≤85°C | 0.85 | | 6.0 | V |
| V DD | Operating Voltage | R3133 | Topt=25°C | 0.80 | | 6.0 | V |
| | | K3133 | –40°C≤Topt≤85°C | 0.90 | | 6.0 | |
| VDET | Detector Threshold | | | V _{DET} × 0.98 | | V _{DET} × 1.02 | V |
| lss1 | Supply Current1 | V _{DD} =V _{DET} -0. | 1V, Iout=0A | | | 2.0 | μΑ |
| Iss2 | Supply Current2 | VDD=VDET+0. | 1V, Iоυт=0A | | | 2.0 | μА |
| | Supply Current3 | | V _{DET} <1.6V | | | 3.6 | μА |
| lss3 | | VDD=6.0V, | 1.6V≤V _{DET} <2.7V | | | 3.0 | |
| | | 2.7V≤V _{DET} | | | | 2.5 | |
| Vон | "H" Output Voltage | | Refer to the follo | wing tab | le. | | |
| Vol | "L" Output Voltage | | Refer to the follo | wing tab | le. | | |
| RMR | MR pin pull-up resistance | Topt=25°C | | 0.5 | 1.0 | 4.0 | ΜΩ |
| Trst* | Output Delay Time for detect | V _{DD} =V _{DET} to | V _{DD} =V _{DET} to V _{DET} -0.1V | | 15 | | μS |
| Tdelay | Output Delay Time for release | V _{DD} =0.8V to V _{DET} +1.0V | | 204 | 240 | 276 | ms |
| $\Delta V_{DET}/\Delta T_{opt}$ | Detector Threshold Temperature Coefficient | –40°C≤Topt≤ | :85°C | | ±100 | | ppm/ °C |

^{*)} Guaranteed by design, not mass production tested.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

• "H" Output Voltage (Voн) table

Topt=25°C

| Products | Те | st Conditions | Min. | Тур. | Max. | Unit |
|------------|-----------------------------|--|---------------------|------|------|------|
| | V _{DET} <1.2V | $V_{DD}=V_{DET}+0.1V$, $I_{OH}=-50\mu A$ | | | | |
| R3132xxxEC | 1.2V≤V _{DET} <2.0V | V _{DD} =V _{DET} +0.1V, I _{OH} =-150μA | 0.0.1/ | | | V |
| R3132XXXEC | 2.0V≤V _{DET} <3.1V | V _{DD} =V _{DET} +0.1V, I _{OH} =-500μA | 0.8×V _{DD} | | | V |
| | 3.1V≤V _{DET} | V _{DD} =V _{DET} +0.1V, I _{OH} =-800μA | | | | |
| | V _{DET} <1.2V | VDD=VDET-0.1V, IOH=-10μA | | | | |
| D2122vovEC | 1.2V≤V _{DET} <2.0V | V _{DD} =V _{DET} -0.1V, I _{OH} =-100μA | 0.0.1/ | | | V |
| R3133xxxEC | 2.0V≤V _{DET} <3.1V | VDD=VDET-0.1V, IOH=-500μA | 0.8×V _{DD} | | | V |
| | 3.1V≤V _{DET} | VDD=VDET-0.1V, IOH=-800μA | | | | |

VDET is a set value.

• "L" Output Voltage (Vol) table

Topt=25°C

| Symbol | Item | Test Conditions | Min. | Тур. | Max. | Unit |
|------------|-----------------------------|--------------------------|------|------|------|------|
| | V _{DET} <1.2V | VDD=VDET-0.1V, IOL=20μA | | | | |
| R3132xxxEx | 1.2V≤V _{DET} <1.6V | VDD=VDET-0.1V, IOL=750μA | | | 0.3 | V |
| R3132XXXEX | 1.6V≤V _{DET} <3.1V | VDD=VDET-0.1V, IOL=1.2mA | | | | |
| | 3.1V≤V _{DET} | VDD=VDET-0.1V, IOL=3.2mA | | | 0.4 | V |
| | V _{DET} <1.2V | Vdd=Vdet+0.1V, Iol=20μA | | | | |
| D2422vovEv | 1.2V≤V _{DET} <1.6V | VDD=VDET+0.1V, IOL=750μA | | | 0.3 | V |
| R3133xxxEx | 1.6V≤V _{DET} <3.1V | VDD=VDET+0.1V, IOL=1.2mA | | | | |
| | 3.1V≤V _{DET} | VDD=VDET+0.1V, IOL=3.2mA | | | 0.4 | V |

VDET is a set value.

DETECTOR THRESHOLD SPECIFICATIONS BY PART NUMBER

• R3132x

| | | Operating Voltage | | Detec | tor Thre | shold | Supply Current 1 | | | |
|-------------|------------|-------------------|-----------------|-------|----------|---------|------------------|---------------|------|------|
| Part Number | | ٧ | 'DD[V] | | | VDET[V] | | Iss1[| μΑ] | |
| | Conditions | Min. | Conditions | Min. | Min. | Тур. | Max. | Conditions | Тур. | Max. |
| R3132x23Ex2 | | | | | 2.274 | 2.320 | 2.366 | | | |
| R3132x26Ex3 | | | | | 2.578 | 2.630 | 2.682 | | 8.0 | |
| R3132x29Ex3 | T | | 1000 T 110500 | 0.05 | 2.872 | 2.930 | 2.988 | VDD=VDET-0.1V | | |
| R3132x30Ex8 | Topt=25°C | 0.75 | –40°C≤Topt≤85°C | 0.85 | 3.019 | 3.080 | 3.141 | Iout=0A | | 2.0 |
| R3132x43Ex8 | | | | | 4.293 | 4.380 | 4.467 | | 0.9 | |
| R3132x46Ex3 | | | | | 4.538 | 4.630 | 4.722 | | | |
| R3132x10Ex | | | | | 0.980 | 1.000 | 1.020 | | | |
| R3132x11Ex | | | | | 1.078 | 1.100 | 1.122 | | | |
| R3132x12Ex | | | | | 1.176 | 1.200 | 1.224 | | | |
| R3132x13Ex | | | | | 1.274 | 1.300 | 1.326 | | | |
| R3132x14Ex | | | | | 1.372 | 1.400 | 1.428 | | | |
| R3132x15Ex | | | | | 1.470 | 1.500 | 1.530 | | | |
| R3132x16Ex | | | | | 1.568 | 1.600 | 1.632 | | | |
| R3132x17Ex | | | | | 1.666 | 1.700 | 1.734 | | | |
| R3132x18Ex | | | | | 1.764 | 1.800 | 1.836 | | 0.8 | |
| R3132x19Ex | | | | | 1.862 | 1.900 | 1.938 | | | |
| R3132x20Ex | | | | | 1.960 | 2.000 | 2.040 | | | |
| R3132x21Ex | | | | | 2.058 | 2.100 | 2.142 | | | |
| R3132x22Ex | | | | | 2.156 | 2.200 | 2.244 | | | |
| R3132x23Ex | | | | | 2.254 | 2.300 | 2.346 | | | |
| R3132x24Ex | | | | | 2.352 | 2.400 | 2.448 | | | |
| R3132x25Ex | | | | | 2.450 | 2.500 | 2.550 | | | |
| R3132x26Ex | | | | | 2.548 | 2.600 | 2.652 | | | |
| R3132x27Ex | | | | | 2.646 | 2.700 | 2.754 | | | |
| R3132x28Ex | | | | | 2.744 | 2.800 | 2.856 | | | |
| R3132x29Ex | | | | | 2.842 | 2.900 | 2.958 | | | |
| R3132x30Ex | Topt=25°C | 0.75 | –40°C≤Topt≤85°C | 0.85 | 2.940 | 3.000 | 3.060 | VDD=VDET-0.1V | | 2.0 |
| R3132x31Ex | • | | • | | 3.038 | 3.100 | 3.162 | lout=0A | | |
| R3132x32Ex | | | | | 3.136 | 3.200 | 3.264 | | | |
| R3132x33Ex | | | | | 3.234 | 3.300 | 3.366 | | | |
| R3132x34Ex | | | | | 3.332 | 3.400 | 3.468 | | | |
| R3132x35Ex | | | | | 3.430 | 3.500 | 3.570 | | | |
| R3132x36Ex | | | | | 3.528 | 3.600 | 3.672 | | | |
| R3132x37Ex | | | | | 3.626 | 3.700 | 3.774 | | | |
| R3132x38Ex | | | | | 3.724 | 3.800 | 3.876 | | | |
| R3132x39Ex | | | | | 3.822 | 3.900 | 3.978 | 1 | 0.9 | |
| R3132x40Ex | | | | | 3.920 | 4.000 | 4.080 | 1 | | |
| R3132x41Ex | | | | | 4.018 | 4.100 | 4.182 | | | |
| R3132x42Ex | | | | | 4.116 | 4.200 | 4.284 | | | |
| R3132x43Ex | | | | | 4.214 | 4.300 | 4.386 | 1 | | |
| R3132x44Ex | | | | | 4.312 | 4.400 | 4.488 | 1 | | |
| R3132x45Ex | | | | | 4.410 | 4.500 | 4.590 | 1 | | |
| R3132x46Ex | | | | | 4.508 | 4.600 | 4.692 | 1 | | |
| R3132x47Ex | | | | | 4.606 | 4.700 | 4.794 | 1 | | |
| R3132x48Ex | | | | | 4.704 | 4.800 | 4.896 | | | |
| R3132x49Ex | | | | | 4.802 | 4.900 | 4.998 | | | |
| R3132x50Ex | | | | | 4.900 | 5.000 | 5.100 | | | |

| Supply Cu | ırrent 2 | | Supply C | Surrent 3 | 3 "H" Output V | | age | | |
|--------------------------|----------|------|------------|-----------|----------------|---|------|--|-------------|
| Iss2[µ | ıA] | | Iss3[| μΑ] | | VoH[V] | | | |
| Conditions | Тур. | Max. | Conditions | Тур. | Max. | Conditions | Min. | | |
| VDD=VDET+0.1V | 0.8 | 2.0 | VDD=6.0V | 1.2 | 3.0 | Vdd=Vdet+0.1V Ioh=–500μA | 0.8× | | |
| Iout=0A | 0.6 | 2.0 | Іоит=0А | 1.0 | 2.5 | VDD=VDET+0.1V IOH=-800μA | VDD | | |
| | | | | | | Vdd=Vdet+0.1V Ioн=-50µA | | | |
| | | | | 3.6 | | | | | |
| | | | | 1.4 | | Vdd=Vdet+0.1V Іон=–150µA | | | |
| | | | | | 3.0 | | _ | | |
| | | | | 1.2 | | V _{DD} =V _{DET} +0.1V Iон=–500μA | | | |
| Vdd=Vdet+0.1V Iout=0A | 0.8 | 0.8 | 0.8 | 2.0 | VDD=6.0V | | | | 0.8× VDD |
| IOUT=UA | | | Iout=0A | 1.0 | 2.5 | Vdd=Vdet+0.1V Iон=–800µA | · | | |
| | | | | 0.8 | | | | | |

| | "L" Output Vo | oltage | MR pin "H" Voltage | | MR pin "L" l Voltage | | MR pin p | ull-up re | esistanc | е | | |
|-------------|---------------|---------|-----------------------|----------|-------------------------|-------------|------------|-----------|----------|------|-----|--|
| Part Number | Vol[V] | | VIH[V] | | Vı∟[V] | | | RMR[MΩ] |] | | | |
| | Conditions | Max. | Conditions | Min. | Conditions | Max. | Conditions | Min. | Тур. | Max. | | |
| R3132x23Ex2 | | | | | | | | | | | | |
| R3132x26Ex3 | VDD=VDET-0.1V | | | | | | | | | | | |
| R3132x29Ex3 | IoL=+1.2mA | | | 0.3 | | 0.75× | | 0.2× | | | 4.0 | |
| R3132x30Ex8 | 1 | | VDD≥VDET+0.1 | VDD | VDD≥VDET+0.1 | VDD | Topt=25°C | 0.5 | 1.0 | 4.0 | | |
| R3132x43Ex8 | VDD=VDET-0.1V | | 1 | | | | | | | | | |
| R3132x46Ex3 | IoL=+3.2mA | 0.4 | | | | | | | | | | |
| R3132x10Ex | VDD=VDET-0.1V | | | | | | | | | | | |
| R3132x11Ex | Iol=+20μA | | | | | | | | | | | |
| R3132x12Ex | | | | | | | | | | | | |
| R3132x13Ex | VDD=VDET-0.1V | | | | | | | | | | | |
| R3132x14Ex | Iol=+750μA | | | | | | | | | | | |
| R3132x15Ex | 1 | | | | | | | | | | | |
| R3132x16Ex | | | | | | | | | | | | |
| R3132x17Ex | 1 | | | | | | | | | | | |
| R3132x18Ex | | | | | | | | | | | | |
| R3132x19Ex | | | | | | | | | | | | |
| R3132x20Ex | | 0.3 | | | | | | | | | | |
| R3132x21Ex | | | | | | | | | | | | |
| R3132x22Ex | Ī., ,, ,,,, | | | | | | | | | | | |
| R3132x23Ex | VDD=VDET-0.1V | | | | | | | | | | | |
| R3132x24Ex | loL=+1.2mA | | | | | | | | | | | |
| R3132x25Ex | | | | | | | | | | | | |
| R3132x26Ex | | | | | | | | | | | | |
| R3132x27Ex | | | | | | | | | | | | |
| R3132x28Ex | | | | | | | | | | | | |
| R3132x29Ex | | | | | | | | | | | | |
| R3132x30Ex | | | VDD≥VDET+0.1 | 0.75× | VDD≥VDET+0.1 | 0.2× VDD | Topt=25°C | 0.5 | 1.0 | 4.0 | | |
| R3132x31Ex | | | | VDD | | VDD | | | | | | |
| R3132x32Ex | | | | | | | | | | | | |
| R3132x33Ex | | | | | | | | | | | | |
| R3132x34Ex | | | | | | | | | | | | |
| R3132x35Ex | | | | | | | | | | | | |
| R3132x36Ex | 1 | | | | | | | | | | | |
| R3132x37Ex | 1 | | | | | | | | | | | |
| R3132x38Ex | 1 | | | | | | | | | | | |
| R3132x39Ex | 1 | | | | | | | | | | | |
| R3132x40Ex | VDD=VDET-0.1V | 0.4 | | | | | | | | | | |
| R3132x41Ex | IoL=+3.2mA | 0.4 | | | | | | | | | | |
| R3132x42Ex | | | | | | | | | | | | |
| R3132x43Ex | 1 | | | | | | | | | | | |
| R3132x44Ex | | | | | | | | | | | | |
| R3132x45Ex | 1 | | | | | | | | | | | |
| R3132x46Ex | 1 | | | | | | | | | | | |
| R3132x47Ex | 1 | | | | | | | | | | | |
| R3132x48Ex | 1 | | | | | | | | | | | |
| R3132x49Ex | 1 | | | | | | | | | | | |
| R3132x50Ex | 1 | <u></u> | | <u> </u> | | <u> </u> | | | | | | |

| Output Dela | | Detector Thres Temperature Coe | fficient | | |
|-------------------------------------|----------|-----------------------------------|----------|-----------------|------|
| | lelay[ms | ΔVDET/ΔTopt[pp | | | |
| Conditions | Min. | Тур. | Max. | Conditions | Тур. |
| VDD=0.8V→ VDET+1.0V Topt=25°C | 204 | 240 | 276 | –40°C≤Topt≤85°C | ±100 |
| VDD=0.8V→ VDET+1.0V Topt=25°C | 204 | 240 | 276 | -40°C≤Topt≤85°C | ±100 |

• R3133x

| Part Number | Operating Voltage | | | | Detector Threshold | | | Supply Current 1 | | |
|--------------|-------------------|------|--|------|--------------------|---------|-------|--------------------------|------|------|
| | VDD[V] | | | | | VDET[V] | | Iss1[μA] | | |
| | Conditions | Min. | Conditions | Min. | Min. | Тур. | Max. | Conditions | Тур. | Max. |
| R3133x23Ex2 | | | | | 2.274 | 2.320 | 2.366 | | 0.0 | |
| R3133x26Ex3 | | | | | 2.578 | 2.630 | 2.682 | | 8.0 | |
| R3133x29Ex3 | T 250C | 0.00 | 4000 <t+<0500< td=""><td rowspan="4">0.90</td><td>2.872</td><td>2.930</td><td>2.988</td><td>VDD=VDET-0.1V</td><td></td><td rowspan="4">2.0</td></t+<0500<> | 0.90 | 2.872 | 2.930 | 2.988 | VDD=VDET-0.1V | | 2.0 |
| R3133x30Ex8 | Topt=25°C | 0.80 | –40°C≤Topt≤85°C | | 3.019 | 3.080 | 3.141 | Iout=0A | 0.9 | |
| R3133x43Ex8 | | | | | 4.293 | 4.380 | 4.467 | | | |
| R3133x46Ex3 | | | | | 4.538 | 4.630 | 4.722 | | | |
| R3133x10Ex | | | | | 0.980 | 1.000 | 1.020 | | | |
| R3133x11Ex | | | | | 1.078 | 1.100 | 1.122 | | | |
| R3133x12Ex | | | | | 1.176 | 1.200 | 1.224 | | | |
| R3133x13Ex | | | | | 1.274 | 1.300 | 1.326 | Vdd=Vdet-0.1V Iout=0A | | |
| R3133x14Ex | | | | | 1.372 | 1.400 | 1.428 | | | 2.0 |
| R3133x15Ex | | | | | 1.470 | 1.500 | 1.530 | | 0.8 | |
| R3133x16Ex | | | | | 1.568 | 1.600 | 1.632 | | | |
| R3133x17Ex | | | | | 1.666 | 1.700 | 1.734 | | | |
| R3133x18Ex | | | | | 1.764 | 1.800 | 1.836 | | | |
| R3133x19Ex | | | | | 1.862 | 1.900 | 1.938 | | | |
| R3133x20Ex | | | | | 1.960 | 2.000 | 2.040 | | | |
| R3133x21Ex | | | | | 2.058 | 2.100 | 2.142 | | | |
| R3133x22Ex | | | | | 2.156 | 2.200 | 2.244 | | | |
| R3133x23Ex | | | | | 2.254 | 2.300 | 2.346 | | | |
| R3133x24Ex | | | | | 2.352 | 2.400 | 2.448 | | | |
| R3133x25Ex | | | | | 2.450 | 2.500 | 2.550 | | | |
| R3133x26Ex | | | | | 2.548 | 2.600 | 2.652 | | | |
| R3133x27Ex | | | | | 2.646 | 2.700 | 2.754 | | | |
| R3133x28Ex | | | | | 2.744 | 2.800 | 2.856 | | | |
| R3133x29Ex | | 0.80 | | | 2.842 | 2.900 | 2.958 | | | |
| R3133x30Ex | Topt=25°C | | –40°C≤Topt≤85°C | 0.90 | 2.940 | 3.000 | 3.060 | | | |
| R3133x31Ex | | | | | 3.038 | 3.100 | 3.162 | | | |
| R3133x32Ex | | | | | 3.136 | 3.200 | 3.264 | | | |
| R3133x33Ex | | | | | 3.234 | 3.300 | 3.366 | | | |
| R3133x34Ex | | | | | 3.332 | 3.400 | 3.468 | | | |
| R3133x35Ex | | | | | 3.430 | 3.500 | 3.570 | | | |
| R3133x36Ex | | | | | 3.528 | 3.600 | 3.672 | | | |
| R3133x37Ex | | | | | 3.626 | 3.700 | 3.774 | | | |
| R3133x38Ex | | | | | 3.724 | 3.800 | 3.876 | | | |
| R3133x39Ex | | | | | 3.822 | 3.900 | 3.978 | | | |
| R3133x40Ex | | | | | 3.920 | 4.000 | 4.080 | 1 | | |
| R3133x41Ex | | | | | 4.018 | | 4.182 | | | |
| R3133x42Ex | | | | | 4.116 | 4.200 | 4.284 | | | |
| R3133x43Ex | | | | | 4.214 | 4.300 | 4.386 | | | |
| R3133x44Ex | | | | | 4.312 | 4.400 | 4.488 | | | |
| R3133x45Ex | | | | | 4.410 | 4.500 | 4.590 | | | |
| R3133x46Ex | | | | | 4.508 | 4.600 | 4.692 | 1 | | |
| R3133x47Ex | | | | | 4.606 | 4.700 | 4.794 | 1 | | |
| R3133x48Ex | | | | | 4.704 | 4.800 | 4.896 | 1 | | |
| R3133x49Ex | | | | | 4.802 | 4.900 | 4.998 | 1 | | |
| IND IDDA#BEX | | | | | 4.900 | 5.000 | 5.100 | - I | | |

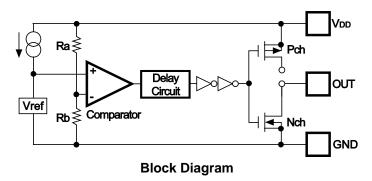
| Supply Current 2 | | Supply Current 3 | | | "H" Output Voltage | | | |
|------------------|------|------------------|---------------------|------|--------------------|-----------------------------|-------------|--|
| Iss2[μA] | | | Iss₃[μA] | | | Voн[V] | | |
| Conditions | Тур. | Max. | Conditions | Тур. | Max. | Conditions | Min. | |
| VDD=VDET+0.1V | 0.8 | 2.0 | Vdd=6.0V Iout=0A | 1.2 | 3.0 | VDD=VDET-0.1V IOH=-500μA | 0.8× Vdd | |
| lout=0A | | | | 1.0 | 2.5 | VDD=VDET-0.1V IOH=-800μA | | |
| | | | Vpd=6.0V lout=0A | | 3.6 | VDD=VDET-0.1V IOH=-10μA | | |
| | | | | 1.4 | | Von Voet 0.4V | | |
| | 0.8 | | | 1.4 | | VDD=VDET-0.1V IOH=-100μA | | |
| | | | | | 3.0 | VDD=VDET-0.1V IOH=-500μA | | |
| | | | | 1.2 | | | | |
| VDD=VDET+0.1V | | 2.0 | | 1.0 | | | 0.8× Vdd | |
| Iout=0A | | | | | 2.5 | VDD=VDET-0.1V IOH=-800μA | VOD | |
| | | | | 0.8 | | | | |

| | "L" Output Voltage VoL[V] | | MR pin "H" Input Voltage Vін[V] | | MR pin "L" Input Voltage Vı∟[V] | | MR pin pull-up resistance R _{MR} [MΩ] | | | |
|-------------|-----------------------------|------|---------------------------------------|--------------|---------------------------------------|-------------|---|------|------|------|
| Part Number | | | | | | | | | | |
| | Conditions | Max. | Conditions | Min. | Conditions | Max. | Conditions | Min. | Тур. | Max. |
| R3133x23Ex2 | | | | | | | | | | |
| R3133x26Ex3 | VDD=VDET+0.1V | 0.2 | | | | | | | | 4.0 |
| R3133x29Ex3 | IoL=+1.2mA | 0.3 | VDD≥VDET+0.1 | 0.75× VDD | VDD≥VDET+0.1 | 0.2× VDD | Topt=25°C | 0.5 | 1.0 | |
| R3133x30Ex8 | | | | | | | | | | |
| R3133x43Ex8 | VDD=VDET+0.1V | 0.4 | | | | | | | | |
| R3133x46Ex3 | IoL=+3.2mA | 0.4 | | | | | | | | |
| R3133x10Ex | VDD=VDET+0.1V | | | | | | | | | |
| R3133x11Ex | Iol=+20μA | | | | | | | | | |
| R3133x12Ex | | | | | | | | | | |
| R3133x13Ex | VDD=VDET+0.1V | | | | | | | | | |
| R3133x14Ex | IoL=+750μA | | | | VDD≥VDET+0.1 | 0.2× VDD | | | | 4.0 |
| R3133x15Ex | | | | | | | | | | |
| R3133x16Ex | | | | | | | | | | |
| R3133x17Ex | | | | | | | Topt=25°C | 0.5 | 1.0 | |
| R3133x18Ex | | | | | | | | | | |
| R3133x19Ex | | | | | | | | | | |
| R3133x20Ex | | 0.3 | | | | | | | | |
| R3133x21Ex | 1 | | | | | | | | | |
| R3133x22Ex | 1 | | | | | | | | | |
| R3133x23Ex | VDD=VDET+0.1V | | | | | | | | | |
| R3133x24Ex | loL=+1.2mA | | | | | | | | | |
| R3133x25Ex | | | | | | | | | | |
| R3133x26Ex | 1 | | | | | | | | | |
| R3133x27Ex | 1 | | | | | | | | | |
| R3133x28Ex | - | | | | | | | | | |
| R3133x29Ex | 1 | | | | | | | | | |
| R3133x30Ex | | | VDD≥VDET+0.1 | O.75× VDD | | | | | | |
| R3133x31Ex | | | 1 | | | | | | | |
| R3133x32Ex | 1 | | | | | | | | | |
| R3133x33Ex | VDD=VDET+0.1V IOL=+3.2mA | | | | | | | | | |
| R3133x34Ex | | | | | | | | | | |
| R3133x35Ex | | | | | | | | | | |
| R3133x36Ex | | | | | | | | | | |
| R3133x37Ex | | | | | | | | | | |
| R3133x38Ex | | | | | | | | | | |
| R3133x39Ex | | | | | | | | | | |
| R3133x40Ex | | • | | | | | | | | |
| R3133x41Ex | | | | | | | | | | |
| R3133x42Ex | | | | | | | | | | |
| R3133x43Ex | | | | | | | | | | |
| R3133x44Ex | ╡ | | | | | | | | | |
| R3133x45Ex | 1 | | | | | | | | | |
| R3133x46Ex | ╡ | | | | | | | | | |
| R3133x47Ex | ╡ | | | | | | | | | |
| R3133x48Ex | ╡ | | | | | | | | | |
| R3133x49Ex | 1 | | | | | | | | | |
| | ⊣ | | 1 | l | 1 | 1 | | 1 | I | I |

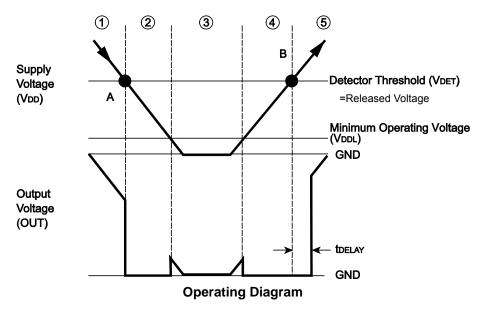
| Output Dela | | Detector Threshold Temperature Coefficient | | | |
|---|----------|---|------|-----------------|------|
| | lelay[ms | ΔVDET/ΔTopt[ppm/°C] | | | |
| Conditions | Min. | Тур. | Max. | Conditions | Тур. |
| V _{DD} =0.8V→ V _{DET} +1.0V Topt=25°C | 204 | 240 | 276 | –40°C≤Topt≤85°C | ±100 |
| VDD=0.8V→ VDET+1.0V Topt=25°C | 204 | 240 | 276 | -40°C≤Topt≤85°C | ±100 |

OPERATION

Operation of R3132x Series



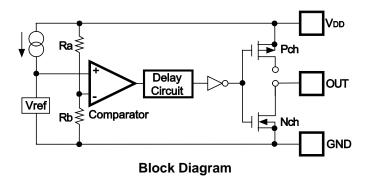
- CMOS Output Type:
 - OUT pin is connected to the drain of Nch Tr. and Pch Tr. in this IC.
- Nch Open Drain Output Type:
 OUT pin is connected to the drain of Nch Tr. in this IC.
 (OUT pin should be pulled up to V_{DD} or an external voltage level.)



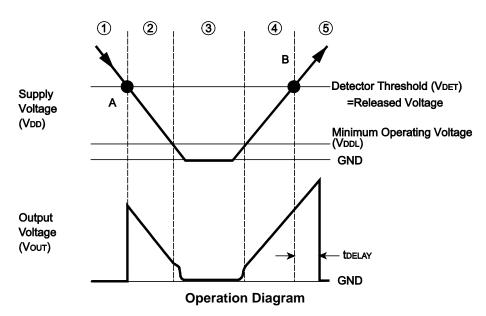
In the above diagram,

- ① Output voltage becomes equal to supply voltage (Nch open drain output type; equal to pull-up Voltage).
- ② When the supply voltage is down to the detector threshold level (Point A), Vref≥V_{DD} × Rb / (Ra+Rb) is true. Then, the output of the comparator is reversed, thus output voltage becomes equal to GND level.
- ③ When the supply voltage is lower than minimum operating voltage, the output of transistor is indefinite, therefore the output is also indefinite.
- ④ Output voltage is equal to GND level.
- ⑤ When the supply voltage is higher than the released voltage (Point B), Vref≤V_{DD} × Rb / (Ra+Rb) is true. Then the output of the comparator is reversed, thus the output voltage becomes equal to the supply voltage (Nch open drain output type; equal to pull-up voltage).
- * There is no hysteresis range between the detector threshold and the released voltage.

Operation of R3133x Series



- CMOS Output Type:
 Out pin is connected to the drain of Nch Tr. and Pch Tr. in this IC.
- Nch Open Drain Output Type:
 Out pin is connected to the drain of Nch Tr. in this IC.
 (OUT pin should be pulled up to V_{DD} or an external voltage level.)

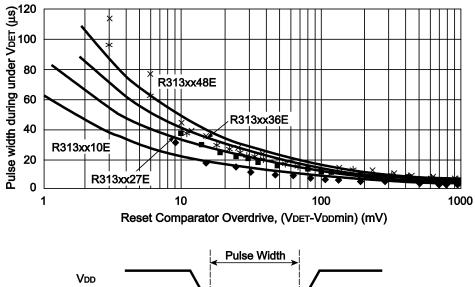


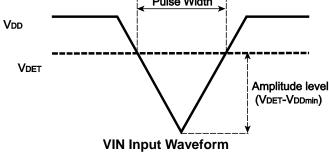
In the above diagram,

- ① Output voltage becomes equal to GND level.
- ② When the supply voltage is down to the detector threshold level (Point A), Vref≥V_{DD} × Rb / (Ra+Rb) is true. Then, the output of the comparator is reversed, thus output voltage becomes equal to the supply voltage (Nch open drain output type; equal to pull-up voltage).
- ③ When the supply voltage is lower than minimum operating voltage, the output of transistor is indefinite, therefore the output is also indefinite. (Nch open drain output type; the output voltage level is equal to pull-up voltage.)
- ④ Output voltage is equal to the supply voltage. (Nch open drain output type; equal to pull-up Voltage.)
- ⑤ When the supply voltage is higher than the released voltage (Point B), Vref≤V_{DD} × Rb / (Ra+Rb) is true. Then the output of the comparator is reversed, thus the output voltage becomes equal to GND level after the output delay time.
- * There is no hysteresis range between the detector threshold and the released voltage.

TECHNICAL NOTES

When the IC is released, if a large pulse (glitch) which crosses the detector threshold voltage is in, the IC may not maintain the released condition. The amplitude of the pulse (VDET-VDDmin) and the pulse width the IC can maintain the released level is described in the graph as follows:





Notes:

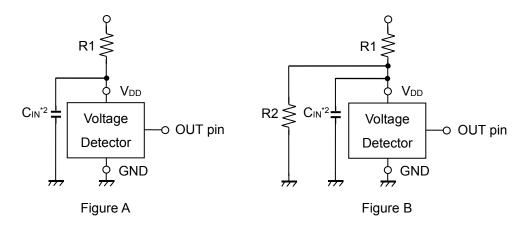
The graph above shows the condition for the maximum transient duration without generating a reset. If the larger amplitude or larger pulse width noise than the graph may be on the V_{DD} , the reset signal may be generated.

When connecting resistors to the device's input pin

When connecting a resistor (R1) to an input of this device, the input voltage decreases by [Device's Consumption Current] x [Resistance Value] only. And, the cross conduction current*1, which occurs when changing from the detecting state to the release state, is decreased the input voltage by [Cross Conduction Current] x [Resistance Value] only. And then, this device will enter the re-detecting state if the input voltage reduction is larger than the difference between the detector voltage and the released voltage.

When the input resistance value is large and the VDD is gone up at mildly in the vicinity of the released voltage, repeating the above operation may result in the occurrence of output.

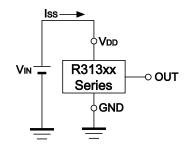
As shown in Figure A/B, set R1 to become 100 k Ω or less as a guide, and connect C_{IN} of 0.1 μ F and more to between the input pin and GND. Besides, make evaluations including temperature properties under the actual usage condition, with using the evaluation board like this way. As a result, make sure that the cross conduction current has no problem.



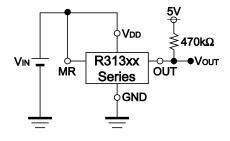
^{*1} In the CMOS output type, a charging current for OUT pin is included.

^{*2} Note the bias dependence of capacitors.

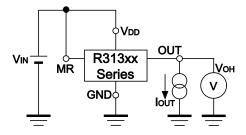
TEST CIRCUITS



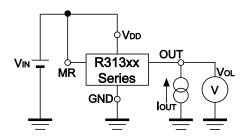
Supply Current Test Circuit



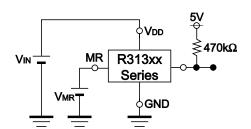
Detector Threshold Test Circuit (CMOS Output type; pull-up part is not necessary.)



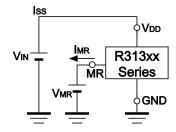
"H" Output Voltage Test Circuit (CMOS Output Type only)



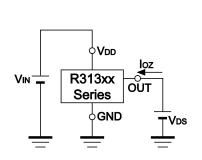
"L" Output Voltage Test Circuit



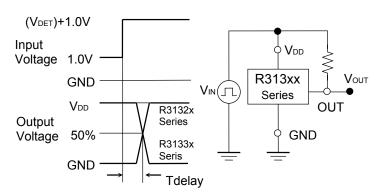
MR pin Input Voltage Test Circuit (CMOS Output type; pull-up part is not necessary.)



MR pin Pull-up Resistance Test Circuit



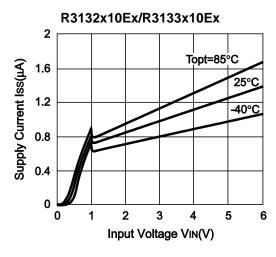
Off Leakage Current Test Circuit

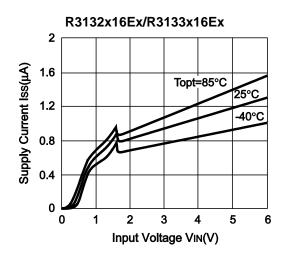


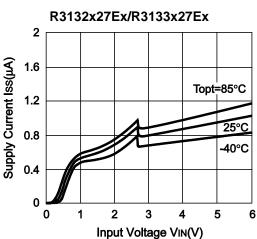
Output Delay Time Test Circuit (CMOS Output type; pull-up is not necessary.)

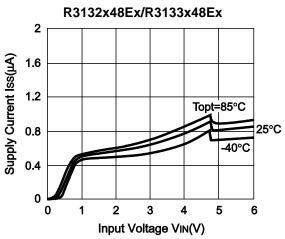
TYPICAL CHARACTERISTICS

1) Supply Current vs. Input Voltage

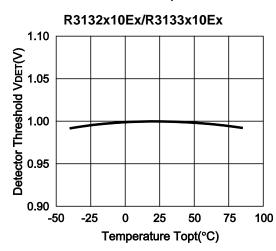


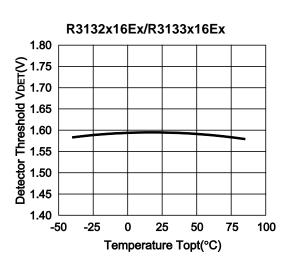


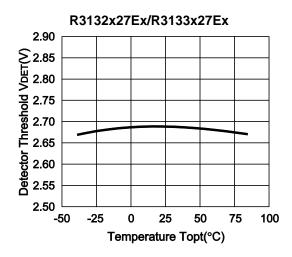


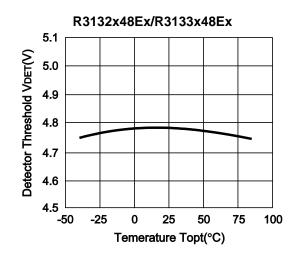


2) Detector Threshold vs. Temperature

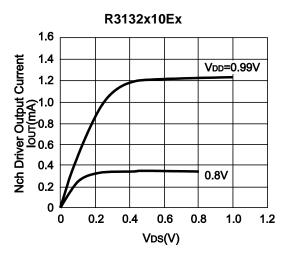


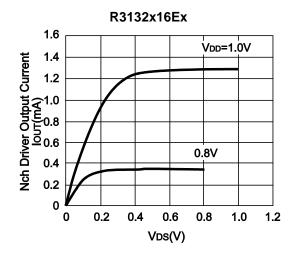


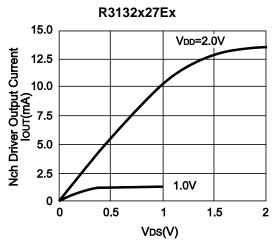


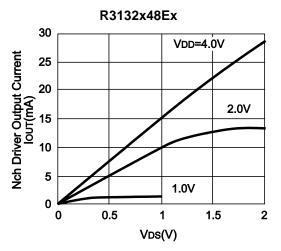


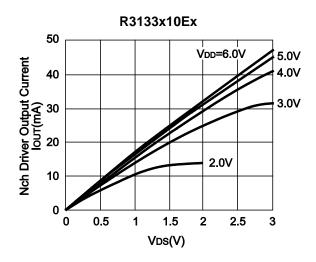
3) Nch Driver Output Current vs. V_{DS} (Topt=25°C)

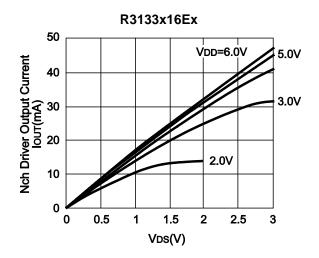


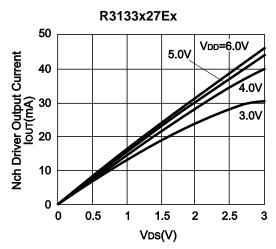


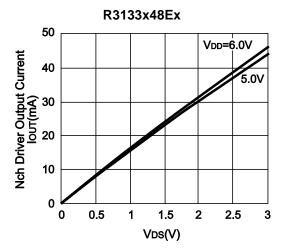




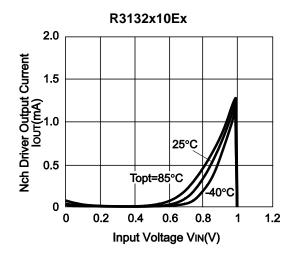


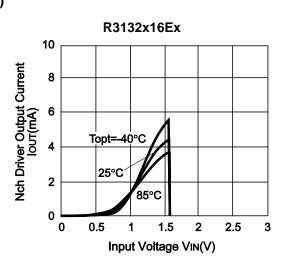


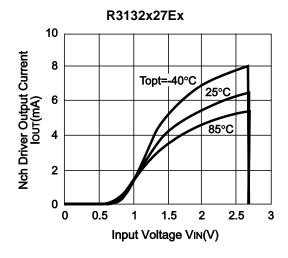


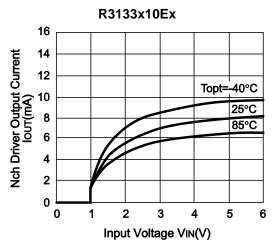


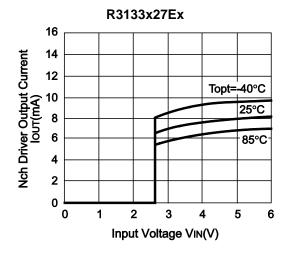
4) Nch Driver Output Current vs. Input Voltage (VDS=0.5V)

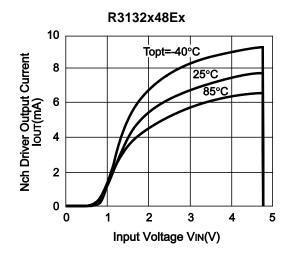


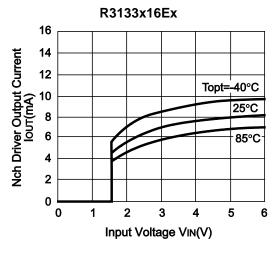


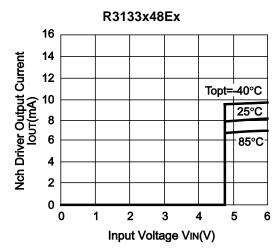




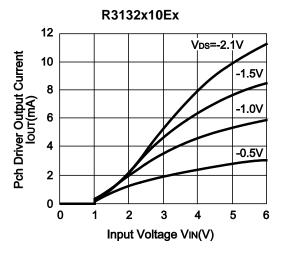


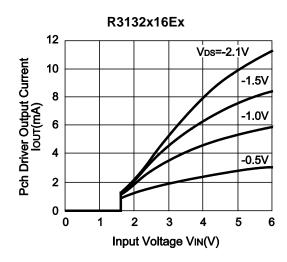


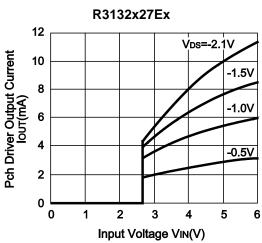


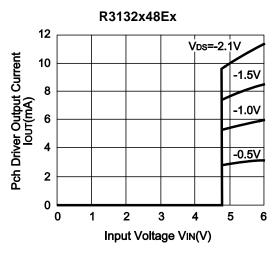


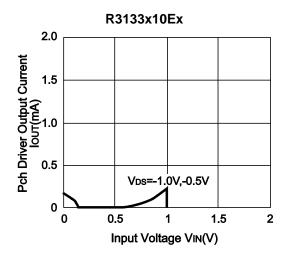
5) Pch Driver Output Current vs. Input Voltage

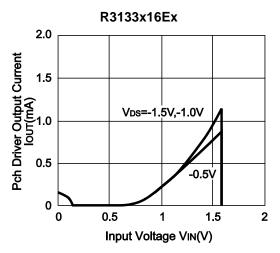


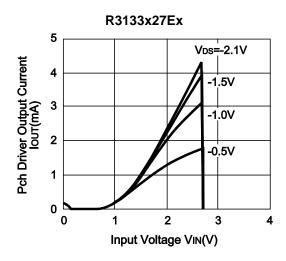


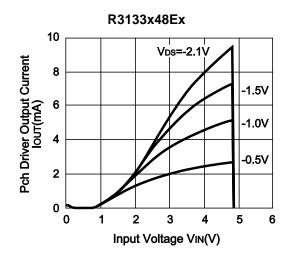




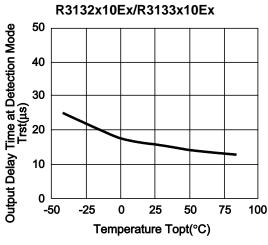


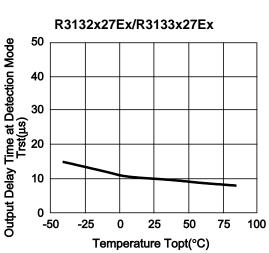


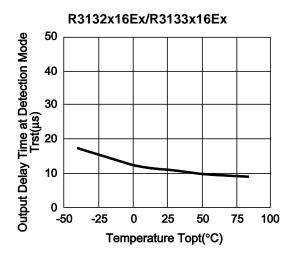


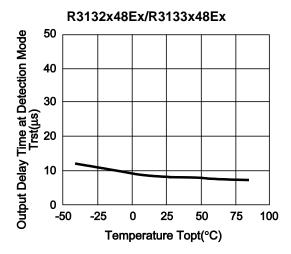


6) Output Delay Time at Detection Mode vs. Temperature

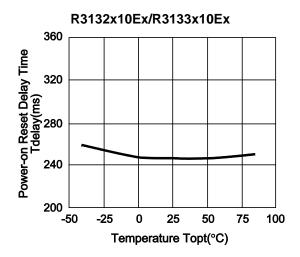


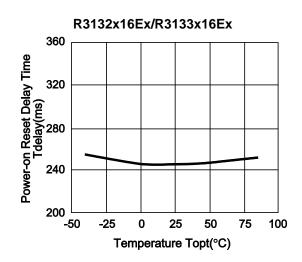


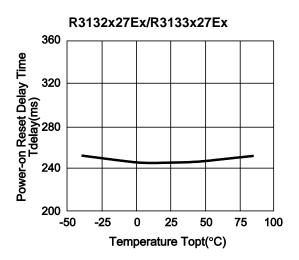


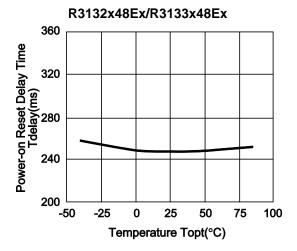


7) Power-on Reset Delay Time vs. Temperature











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